Growth Inside a Corner: Limiting Interface Shape JASON OLE-
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MALLICK, CEA Saclay, France — We investigate a simple model for crystal growth
in which elemental cubes are stochastically deposited onto the inside of a three-
dimensional corner. The interface of this crystal evolves into a deterministic limiting
shape in the long-time limit. We incorporate known results from the corresponding
two-dimensional system and use geometrical symmetries of the three-dimensional
problem to conjecture an equation of motion for the interface profile which we solve
analytically. The agreement between the result of the calculation and simulations
of the growth process is excellent. We also present a generalization of our equation
of interface motion to arbitrary spatial dimension.

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